



HE8051

NPN SILICON TRANSISTOR

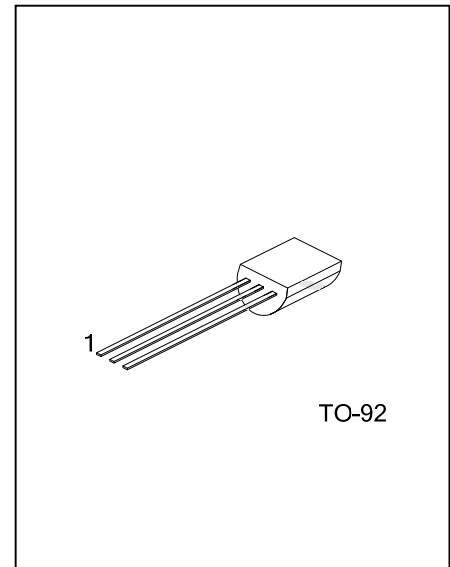
LOW VOLTAGE HIGH CURRENT SMALL SIGNAL NPN TRANSISTOR

DESCRIPTION

The UTC **HE8051** is a low voltage high current small signal NPN transistor, designed for Class B push-pull 2W audio amplifier for portable radio and general purpose applications.

FEATURES

- * Collector current up to 1.5A
- * Collector-Emitter voltage up to 25 V
- * complimentary to UTC **HE8551**

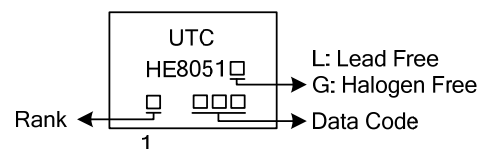


ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
HE8051L-x-T92-B	HE8051G-x-T92-B	TO-92	E	B	C	Tape Box
HE8051L-x-T92-K	HE8051G-x-T92-K	TO-92	E	B	C	Bulk

HE8051L-x-T92-B (1)Packing Type (2)Package Type (3)Rank (4)Lead Plating	(1) B: Tape Box, K: Bulk (2) T92: TO-92 (3) x: refer to Classification of h_{FE2} (4) L: Lead Free, G: Halogen Free
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MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Dissipation ($T_A=25^\circ\text{C}$)	P_C	1	W
Collector Current	I_C	1.5	A
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-40 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

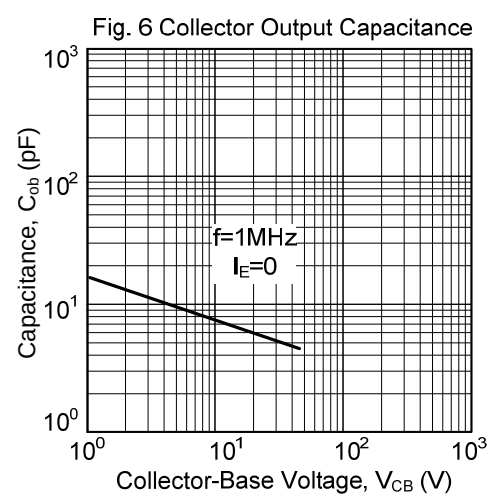
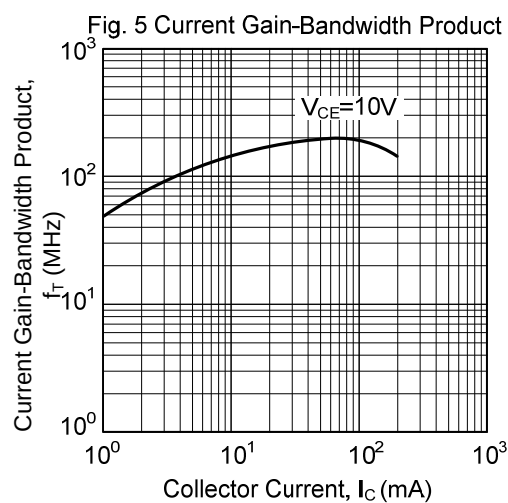
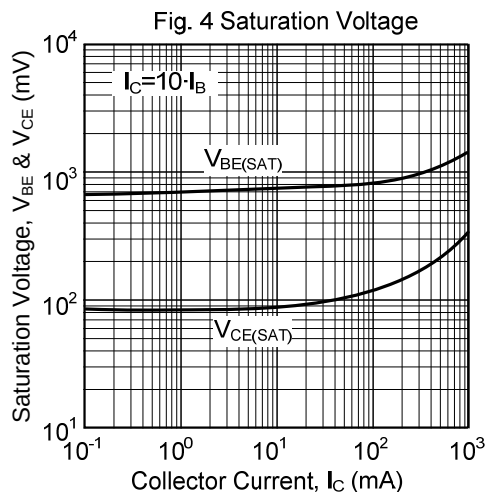
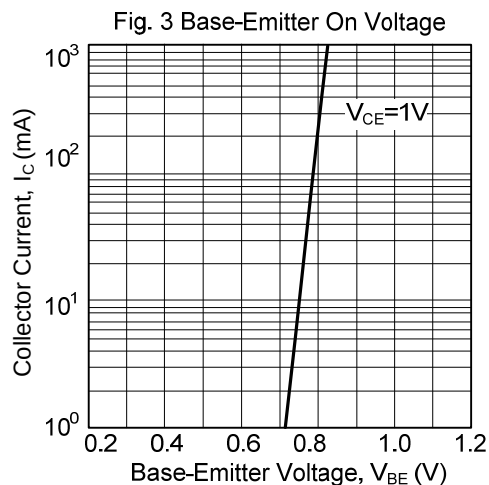
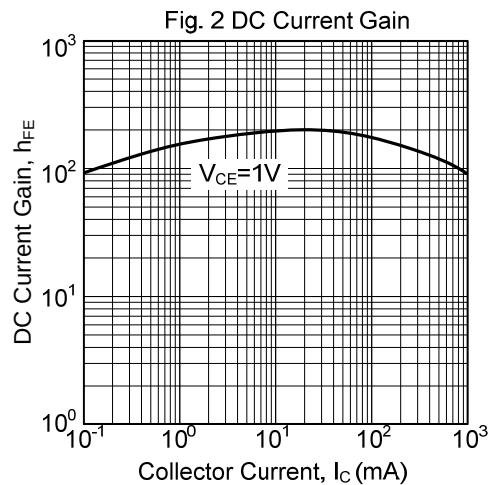
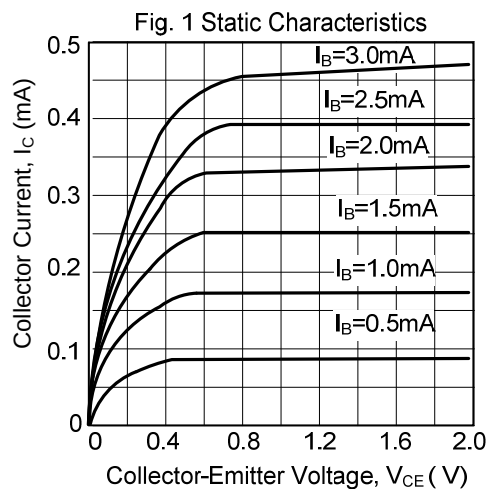
■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=100\mu\text{A}$, $I_E=0$	40			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=2\text{mA}$, $I_B=0$	25			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=100\mu\text{A}$, $I_C=0$	6			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=35\text{V}$, $I_E=0$			100	nA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=6\text{V}$, $I_C=0$			100	nA
DC Current Gain	h_{FE1}	$V_{CE}=1\text{V}$, $I_C=5\text{mA}$	45	135		
	h_{FE2}	$V_{CE}=1\text{V}$, $I_C=100\text{mA}$	85	160	500	
	h_{FE3}	$V_{CE}=1\text{V}$, $I_C=800\text{mA}$	40	110		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=800\text{mA}$, $I_B=80\text{mA}$			0.5	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=800\text{mA}$, $I_B=80\text{mA}$			1.2	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=1\text{V}$, $I_C=10\text{mA}$			1.0	V
Current Gain Bandwidth Product	f_T	$V_{CE}=10\text{V}$, $I_C=50\text{mA}$	100			MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$		9.0		pF

■ CLASSIFICATION OF h_{FE2}

RANK	C	D	E
RANGE	120-200	160-300	250-500

■ TYPICAL CHARACTERISTICS



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